

VS-GB100TH120N Information


For Reference Only

Part Number [VS-GB100TH120N](#)
Manufacturer Vishay Semiconductor Diodes Division
Category Discrete Semiconductor Products
[Transistors - IGBTs - Modules](#)
Description IGBT 1200V 200A 833W INT-A-PAK
Package Double INT-A-PAK (3 + 4)
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


VS-GB100TH120N Specifications

Manufacturer Part Number	VS-GB100TH120N
Manufacturer	Vishay Semiconductor Diodes Division
Category	Discrete Semiconductor Products Transistors - IGBTs - Modules
Package	Double INT-A-PAK (3 + 4)
Series	-
IGBT Type	-
Configuration	Half Bridge
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	200A
Power - Max	833W
Vce(on) (Max) @ Vge, Ic	2.35V @ 15V, 100A
Current - Collector Cutoff (Max)	5mA
Input Capacitance (Cies) @ Vce	8.58nF @ 25V
Input	Standard
NTC Thermistor	No
Operating Temperature	150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	Double INT-A-PAK (3 + 4)
Supplier Device Package	Double INT-A-PAK

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VS-GB100TH120N Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

VS-GB100TH120N Payment Methods



VS-GB100TH120N Shipping Methods



If you have any question about VS-GB100TH120N, please do not hesitate to contact us!

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